# NSS30101LT1G

# Low V<sub>CE(sat)</sub> Transistor, NPN, 30 V, 2.0 A, SOT-23 Package

ON Semiconductor's e<sup>2</sup>PowerEdge family of low  $V_{CE(sat)}$  transistors are miniature surface mount devices featuring ultra low saturation voltage ( $V_{CE(sat)}$ ) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical application are DC–DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e<sup>2</sup>PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

• These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ )						
	Rating	Symbol	Max	Unit		
	Collector-Emitter Voltage	V <sub>CEO</sub>	30	Vdc		
	Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc		
	Emitter-Base Voltage	V <sub>EBO</sub>	5.0	Vdc		
	Collector Current – Continuous	Ι <sub>C</sub>	1.0	А		
	Collector Current – Peak	I <sub>CM</sub>	2.0	А		

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P <sub>D</sub> (Note 1)	310 2.5	mW mW/°C
		2.5	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub> (Note 1)	403	°C/W
Total Device Dissipation $T_A = 25^{\circ}C$	P <sub>D</sub> (Note 2)	710	mW
Derate above 25°C		5.7	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$ (Note 2)	176	°C/W
Total Device Dissipation (Single Pulse < 10 sec.)	P <sub>Dsingle</sub>	575	mW
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

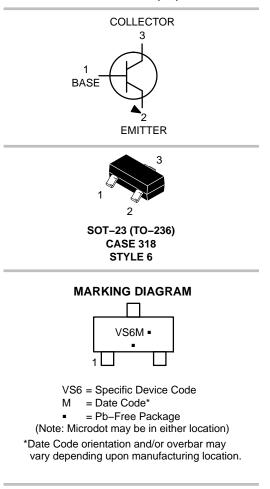
FR-4 @ Minimum Pad.
FR-4 @ 1.0 X 1.0 inch Pad.



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 $\begin{array}{c} 30 \text{ VOLTS} \\ 2.0 \text{ AMPS} \\ \text{NPN LOW V}_{\text{CE(sat)}} \text{ TRANSISTOR} \\ \text{EQUIVALENT R}_{\text{DS(on)}} 100 \text{ m}\Omega \end{array}$ 



### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NSS30101LT1G	SOT–23 (Pb–Free)	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	<u> </u>			
Collector – Emitter Breakdown Voltage ( $I_C = 10 \text{ mAdc}, I_B = 0$ )	V <sub>(BR)CEO</sub>	30	_	Vdc
Collector-Base Breakdown Voltage $(I_C = 0.1 \text{ mAdc}, I_E = 0)$	V <sub>(BR)CBO</sub>	50	-	Vdc
Emitter – Base Breakdown Voltage $(I_E = 0.1 \text{ mAdc}, I_C = 0)$	V <sub>(BR)EBO</sub>	5.0	-	Vdc
Collector Cutoff Current ( $V_{CB} = 30 \text{ Vdc}, I_E = 0$ )	Ісво	_	0.1	μAdc
Collector–Emitter Cutoff Current (V <sub>CES</sub> = 30 Vdc)	I <sub>CES</sub>	_	0.1	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = 4.0 Vdc)	I <sub>EBO</sub>	_	0.1	μAdc
ON CHARACTERISTICS				
DC Current Gain (Note 3) $(I_C = 50 \text{ mA}, V_{CE} = 5.0 \text{ V})$ $(I_C = 0.5 \text{ A}, V_{CE} = 5.0 \text{ V})$ $(I_C = 1.0 \text{ A}, V_{CE} = 5.0 \text{ V})$	h <sub>FE</sub>	300 300 200	_ 900 _	
Collector – Emitter Saturation Voltage (Note 3) ( $I_C = 1.0 \text{ A}, I_B = 100 \text{ mA}$ ) ( $I_C = 0.5 \text{ A}, I_B = 50 \text{ mA}$ ) ( $I_C = 0.1 \text{ A}, I_B = 1.0 \text{ mA}$ )	V <sub>CE(sat)</sub>	- - -	0.200 0.125 0.075	V
Base – Emitter Saturation Voltage (Note 3) $(I_C = 1.0 \text{ A}, I_B = 0.1 \text{ A})$	V <sub>BE(sat)</sub>	_	1.1	V
Base – Emitter Turn–on Voltage (Note 3) ( $I_C = 1.0 \text{ mA}, V_{CE} = 2.0 \text{ V}$ )	V <sub>BE(on)</sub>	_	1.1	V
Cutoff Frequency (I <sub>C</sub> = 100 mA, V <sub>CE</sub> = 5.0 V, f = 100 MHz	f <sub>T</sub>	100	_	MHz
Output Capacitance (f = 1.0 MHz)	C <sub>obo</sub>	_	15	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulsed Condition: Pulse Width =  $300 \ \mu$ sec, Duty Cycle  $\leq 2\%$ 

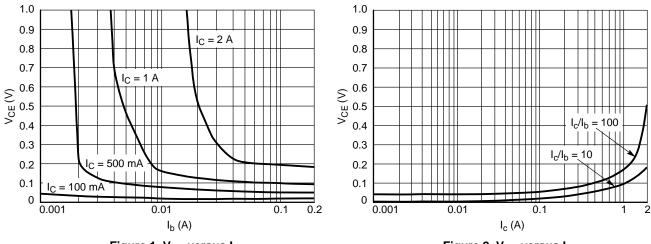


Figure 1.  $V_{CE}$  versus  $I_b$ 

Figure 2.  $V_{CE}$  versus  $I_c$ 

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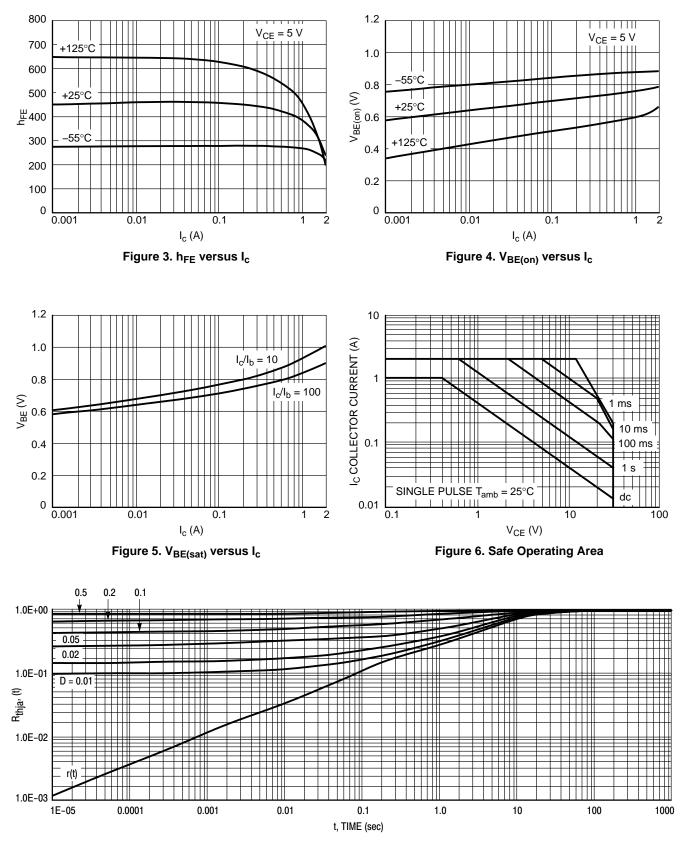


Figure 7. Normalized Thermal Response





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